

L Number	Hits	Search Text	DB	Time stamp
1	223	257/186.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 12:32
2	33	257/186.ccls. and (pin avalanche) and intrinsic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 12:36
3	24	257/186,184,199.ccls. and (wide adj bandgap) and intrinsic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 12:40
4	13	257/186,184,199.ccls. and (wide adj bandgap) with thick\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 13:06
5	1	(ionization adj coefficient) near2 cm	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 13:07
6	8	(ionization adj coefficient) with concentration	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 13:45
7	135	ionization adj coefficient	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 13:51
8	3	("6452221").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/28 13:51
-	248	257/79,99,103.ccls. and mesa	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/25 12:42
-	5	257/81,94,97.ccls. and mesa and (wide adj bandgap) and intrinsic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/25 12:44
-	176	257/81,94,97.ccls. and mesa	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/25 13:00
-	144	257/680,21,85.ccls. and mesa	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/25 14:30
-	15	257/656,458,431.ccls. and (pin adj photodiode) and (APD (avalanche adj photodiode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/25 14:40

-	839	257/458.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 12:56
-	223	257/186.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 12:57
-	2	("6229162").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 13:39
-	0	(avalanche adj photodiodes) with (impact adj layer) with (ionization adj coefficient)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 13:40
-	0	(avalanche adj photodiodes) with (impact adj layer)	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 13:40
-	0	(avalanche adj photodiode) with (impact adj layer)	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 13:41
-	49	(avalanche adj photodiode) and (ionization adj coefficient)	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 13:51
-	1	(avalanche adj photodiode) and (intrinsic adj InAlAs)	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 13:52
-	1	(impact adj layer) and (intrinsic adj InAlAs)	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/26 13:52
-	5	intrinsic adj InAlAs	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/04/28 12:24

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-	5	intrinsic adj InAlAs	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 12:24